

Silicon Standard Recovery Diode

 $V_{RRM} = 400\text{ V} - 1800\text{ V}$
 $I_F = 165\text{ A}$

Features

- High Surge Capability
- Types up to 1800 V V_{RRM}
- Equivalent to SKR130 Series
- Not ESD Sensitive

DO-8 Package

Maximum ratings, at $T_j = 25\text{ °C}$, unless otherwise specified (GKN has leads reversed)

| Parameter | Symbol | Conditions | GKR130/04 | GKR130/08 | GKR130/12 | GKR130/14 | GKR130/16 | GKR130/18 | Unit |
|--|------------|--|------------|------------|------------|------------|------------|------------|------|
| Repetitive peak reverse voltage | V_{RRM} | | 400 | 800 | 1200 | 1400 | 1600 | 1800 | V |
| DC blocking voltage | V_{DC} | | 400 | 800 | 1200 | 1400 | 1600 | 1800 | V |
| Continuous forward current | I_F | $T_C \leq 100\text{ °C}$ | 165 | 165 | 165 | 165 | 165 | 165 | A |
| Surge non-repetitive forward current, Half Sine Wave | $I_{F,SM}$ | $T_C = 25\text{ °C}, t_p = 10\text{ ms}$ | 2500 | 2500 | 2500 | 2500 | 2500 | 2500 | A |
| Operating temperature | T_j | | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | °C |
| Storage temperature | T_{stg} | | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | -55 to 150 | °C |

Electrical characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Conditions | GKR130/04 | GKR130/08 | GKR130/12 | GKR130/14 | GKR130/16 | GKR130/18 | Unit |
|-----------------------|--------|---|-----------|-----------|-----------|-----------|-----------|-----------|------|
| Diode forward voltage | V_F | $I_F = 60\text{ A}, T_j = 25\text{ °C}$ | 1.5 | 1.5 | 1.5 | 1.5 | 1.5 | 1.5 | V |
| Reverse current | I_R | $V_R = V_{RRM}, T_j = 180\text{ °C}$ | 22 | 22 | 22 | 22 | 22 | 22 | mA |

Thermal characteristics

| Parameter | Symbol | Conditions | GKR130/04 | GKR130/08 | GKR130/12 | GKR130/14 | GKR130/16 | GKR130/18 | Unit |
|-------------------------------------|------------|------------|-----------|-----------|-----------|-----------|-----------|-----------|------|
| Thermal resistance, junction - case | R_{thJC} | | 0.35 | 0.35 | 0.35 | 0.35 | 0.35 | 0.35 | K/W |

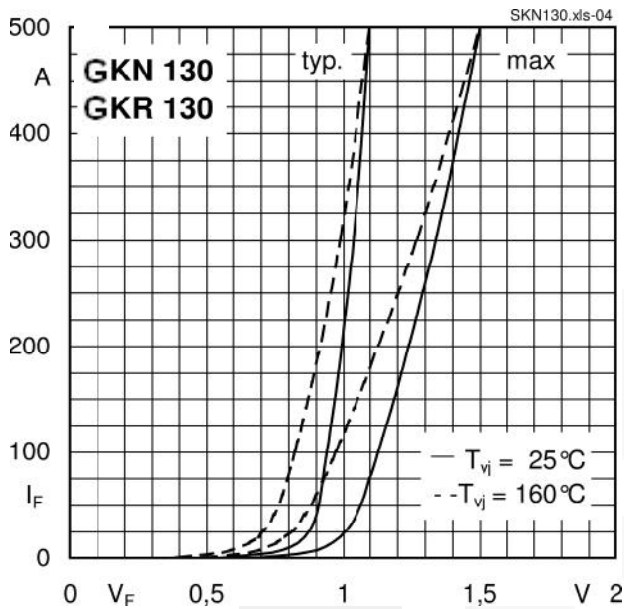


Fig 1: Forward Characteristics

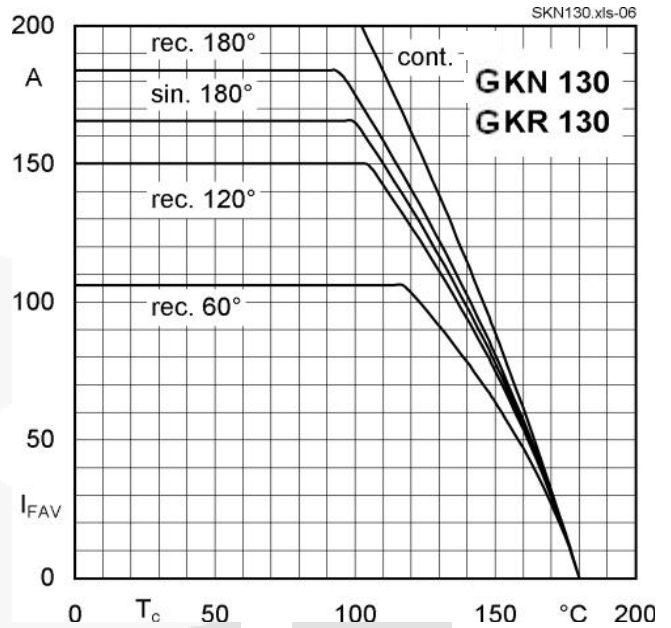


Fig 2: Forward Current vs Case Temp

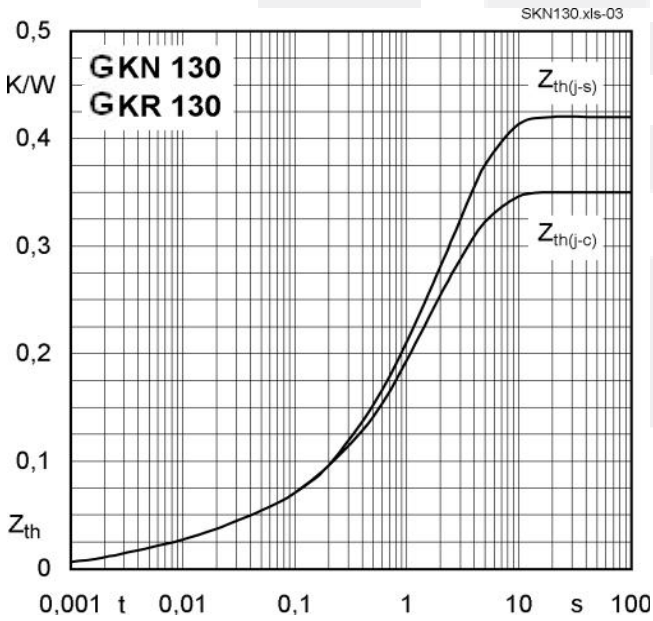


Fig 3: Transient Thermal Impedance vs Time

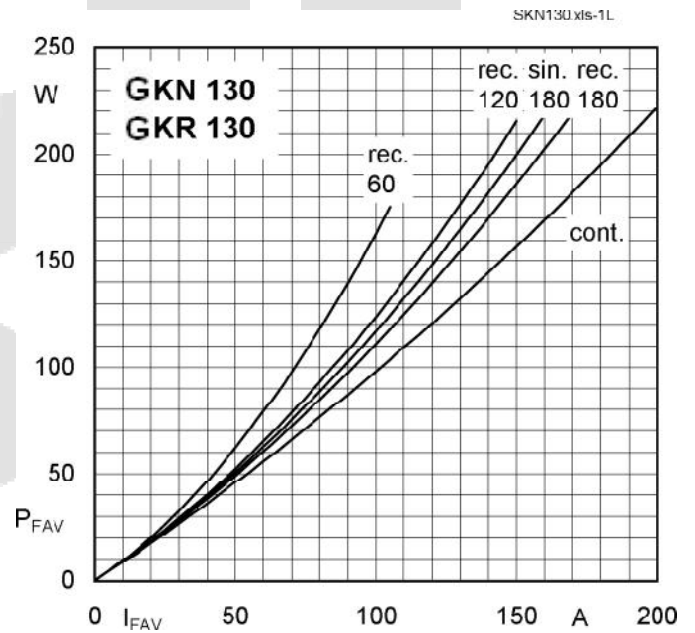
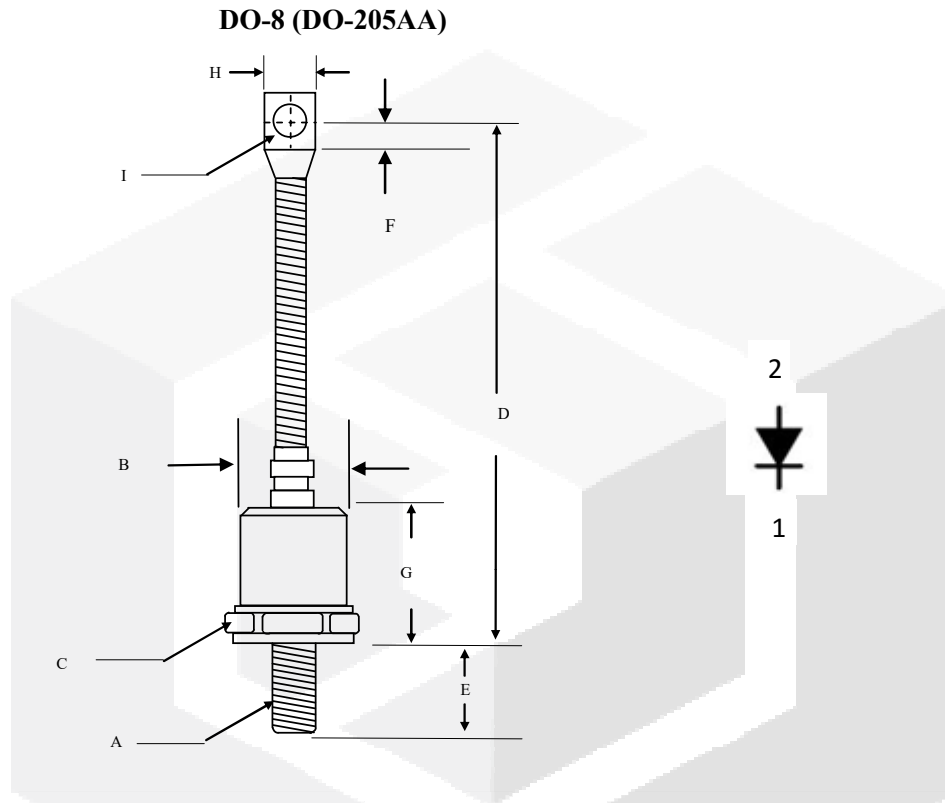


Fig 4: Power Dissipation vs Forward Current

Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



| | Inches | | Millimeters | |
|---|------------|--------|-------------|--------|
| | Min | Max | Min | Max |
| A | 3/8-24 UNF | | | |
| B | ---- | φ0.930 | ---- | φ23.5 |
| C | 1.050 | 1.060 | 26.67 | 26.92 |
| D | 4.300 | 4.700 | 109.22 | 119.38 |
| E | ---- | 0.690 | ---- | 17.00 |
| F | 0.260 | ---- | 6.50 | ---- |
| G | ---- | 0.940 | ---- | 24.00 |
| H | ---- | 0.600 | ---- | 15.23 |
| I | 0.276 | 0.286 | 7.010 | 7.260 |